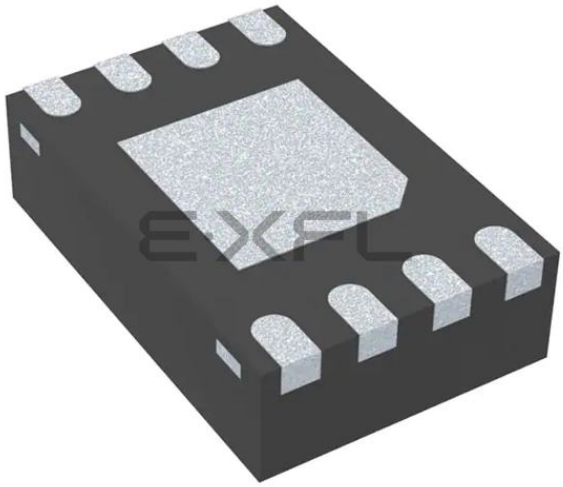

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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	8MHz
Connectivity	-
Peripherals	POR, WDT
Number of I/O	4
Program Memory Size	384B (256 x 12)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16 x 8
Voltage - Supply (Vcc/Vdd)	2V ~ 5.5V
Data Converters	A/D 2x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	8-VFDFN Exposed Pad
Supplier Device Package	8-DFN (2x3)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic10f220-i-mc

4.0 MEMORY ORGANIZATION

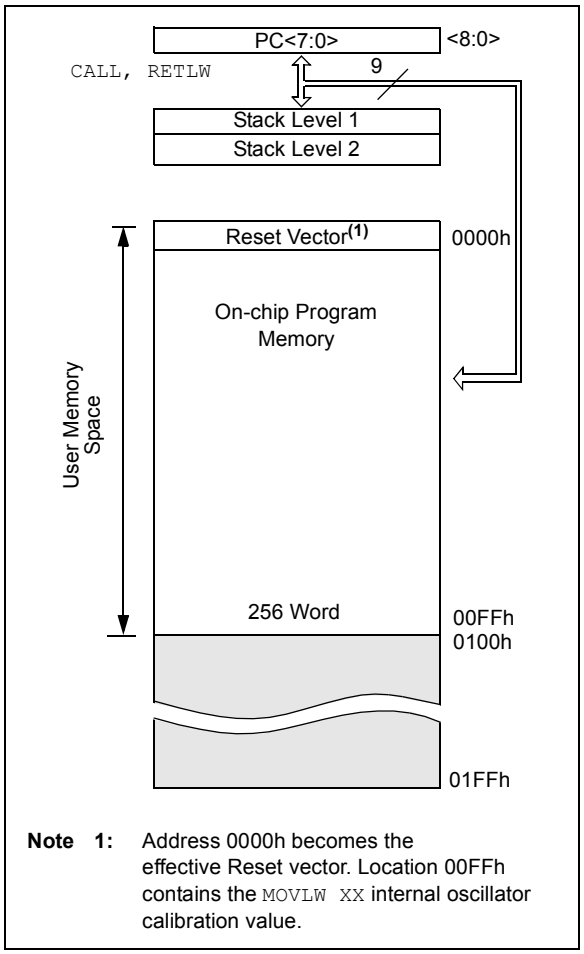
The PIC10F220/222 memories are organized into program memory and data memory. Data memory banks are accessed using the File Select Register (FSR).

4.1 Program Memory Organization for the PIC10F220

The PIC10F220 devices have a 9-bit Program Counter (PC) capable of addressing a 512 x 12 program memory space.

Only the first 256 x 12 (0000h-00FFh) for the PIC10F220 are physically implemented (see Figure 4-1). Accessing a location above these boundaries will cause a wrap-around within the first 256 x 12 space (PIC10F220). The effective Reset vector is at 0000h, (see Figure 4-1). Location 00FFh (PIC10F220) contains the internal clock oscillator calibration value. This value should never be overwritten.

FIGURE 4-1: PROGRAM MEMORY MAP AND STACK FOR THE PIC10F220



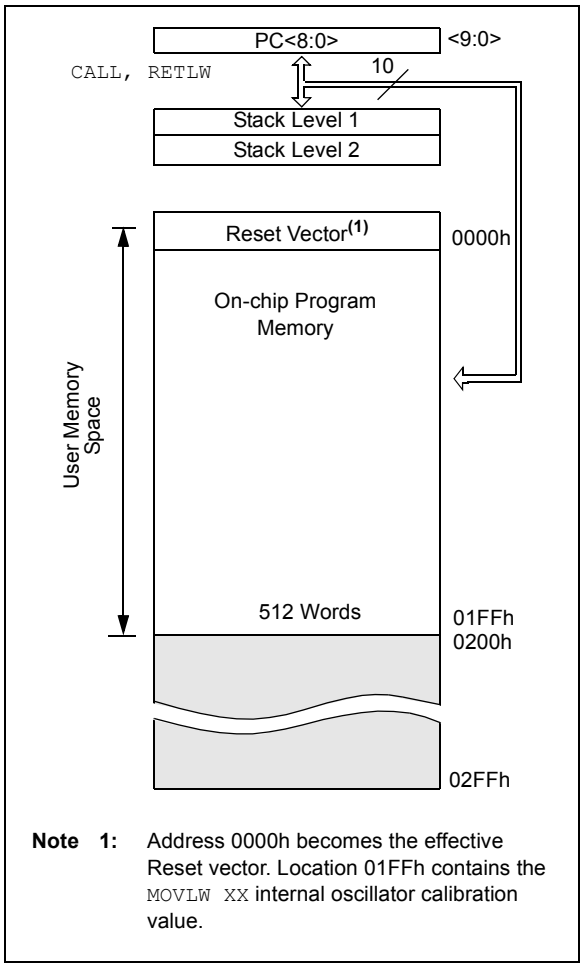
Note 1: Address 0000h becomes the effective Reset vector. Location 00FFh contains the `MOVLW XX` internal oscillator calibration value.

4.2 Program Memory Organization for the PIC10F222

The PIC10F222 devices have a 10-bit Program Counter (PC) capable of addressing a 1024 x 12 program memory space.

Only the first 512 x 12 (0000h-01FFh) for the Mem-High are physically implemented (see Figure 4-2). Accessing a location above these boundaries will cause a wrap-around within the first 512 x 12 space (PIC10F222). The effective Reset vector is at 0000h, (see Figure 4-2). Location 01FFh (PIC10F222) contains the internal clock oscillator calibration value. This value should never be overwritten.

FIGURE 4-2: PROGRAM MEMORY MAP AND STACK FOR THE PIC10F222



Note 1: Address 0000h becomes the effective Reset vector. Location 01FFh contains the `MOVLW XX` internal oscillator calibration value.

4.9 Indirect Data Addressing; INDF and FSR Registers

The INDF register is not a physical register. Addressing INDF actually addresses the register whose address is contained in the FSR register (FSR is a *pointer*). This is indirect addressing.

4.9.1 INDIRECT ADDRESSING

- Register file 09 contains the value 10h
- Register file 0A contains the value 0Ah
- Load the value 09 into the FSR register
- A read of the INDF register will return the value of 10h
- Increment the value of the FSR register by one (FSR = 0A)
- A read of the INDR register now will return the value of 0Ah.

Reading INDF itself indirectly (FSR = 0) will produce 00h. Writing to the INDF register indirectly results in a no-operation (although Status bits may be affected).

A simple program to clear RAM locations 10h-1Fh using Indirect addressing is shown in Example 4-1.

EXAMPLE 4-1: HOW TO CLEAR RAM USING INDIRECT ADDRESSING

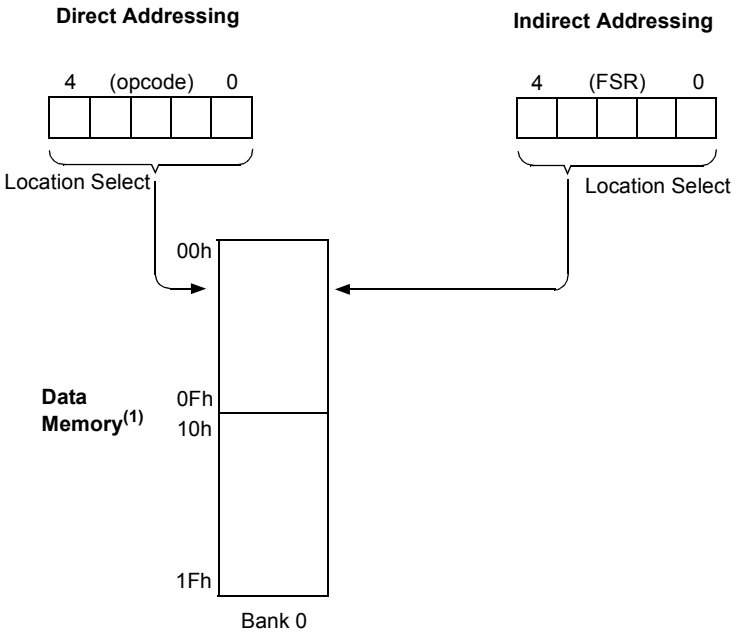
```
        MOVLW   0x10    ;initialize pointer
        MOVWF   FSR     ;to RAM
NEXT    CLRF    INDF    ;clear INDF
                        ;register
        INCF    FSR,F   ;inc pointer
        BTFSC   FSR,4   ;all done?
        GOTO    NEXT    ;NO, clear next
CONTINUE
            :           ;YES, continue
            :
```

The FSR is a 5-bit wide register. It is used in conjunction with the INDF register to indirectly address the data memory area.

The FSR<4:0> bits are used to select data memory addresses 00h to 1Fh.

Note:	Do not use banking. FSR <7:5> are unimplemented and read as '1's.

FIGURE 4-6: DIRECT/INDIRECT ADDRESSING



Note 1: For register map detail, see **Section 4.3 "Data Memory Organization"**.

5.0 I/O PORT

As with any other register, the I/O register(s) can be written and read under program control. However, read instructions (e.g., `MOVF GPIO, W`) always read the I/O pins independent of the pin's Input/Output modes. On Reset, all I/O ports are defined as input (inputs are at high-impedance) since the I/O control registers are all set.

5.1 GPIO

GPIO is an 8-bit I/O register. Only the low-order 4 bits are used (GP<3:0>). Bits 7 through 4 are unimplemented and read as '0's. Please note that GP3 is an input only pin. Pins GP0, GP1 and GP3 can be configured with weak pull-ups and also for wake-up on change. The wake-up on change and weak pull-up functions are not individually pin selectable. If GP3/$\overline{\text{MCLR}}$ is configured as $\overline{\text{MCLR}}$, a weak pull-up can be enabled via the Configuration Word. Configuring GP3 as $\overline{\text{MCLR}}$ disables the wake-up on change function for this pin.

5.2 TRIS Registers

The Output Driver Control register is loaded with the contents of the W register by executing the `TRIS f` instruction. A '1' from a TRIS register bit puts the corresponding output driver in a High-Impedance mode. A '0' puts the contents of the output data latch on the selected pins, enabling the output buffer. The exceptions are GP3, which is input only, and the GP2/T0CKI/FOSC4 pin, which may be controlled by various registers. See Table 5-1.

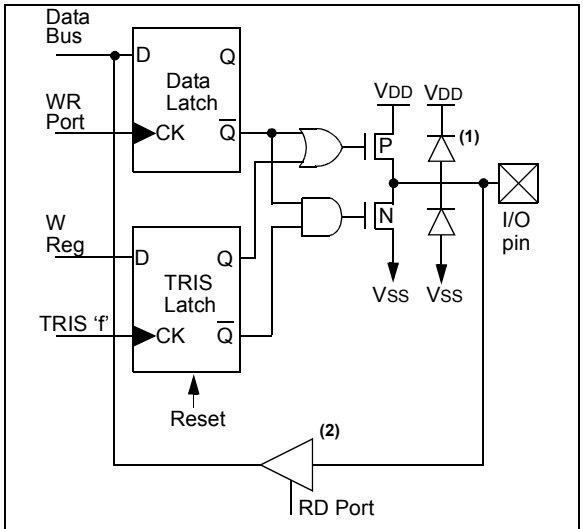
Note:	A read of the ports reads the pins, not the output data latches. That is, if an output driver on a pin is enabled and driven high, but the external system is holding it low, a read of the port will indicate that the pin is low.

The TRIS registers are "write-only" and are set (output drivers disabled) upon Reset.

5.3 I/O Interfacing

The equivalent circuit for an I/O port pin is shown in Figure 5-1. All port pins, except GP3, which is input only, may be used for both input and output operations. For input operations, these ports are non-latching. Any input must be present until read by an input instruction (e.g., `MOVF GPIO, W`). The outputs are latched and remain unchanged until the output latch is rewritten. To use a port pin as output, the corresponding direction control bit in TRIS must be cleared (= 0). For use as an input, the corresponding TRIS bit must be set. Any I/O pin (except GP3) can be programmed individually as input or output.

FIGURE 5-1: EQUIVALENT CIRCUIT FOR A SINGLE I/O PIN



Note 1: I/O pins have protection diodes to V_{DD} and V_{SS}.

2: See Table 3-1 for buffer type.

TABLE 5-1: ORDER OF PRECEDENCE FOR PIN FUNCTIONS

Priority	GP0	GP1	GP2	GP3
1	AN0	AN1	FOSC4	$\overline{\text{MCLR}}$
2	TRIS GPIO	TRIS GPIO	T0CKI	—
3	—	—	TRIS GPIO	—

TABLE 5-2: REQUIREMENTS TO MAKE PINS AVAILABLE IN DIGITAL MODE

Bit	GP0	GP1	GP2	GP3
FOSC4	—	—	0	—
T0CS	—	—	0	—
ANS1	—	0	—	—
ANS0	0	—	—	—
MCLRE	—	—	—	0

Legend: — = Condition of bit will have no effect on the setting of the pin to Digital mode.

NOTES:

6.0 TMR0 MODULE AND TMR0 REGISTER

The Timer0 module has the following features:

- 8-bit timer/counter register, TMR0
- Readable and writable
- 8-bit software programmable prescaler
- Internal or external clock select:
  - Edge select for external clock

Figure 6-1 is a simplified block diagram of the Timer0 module.

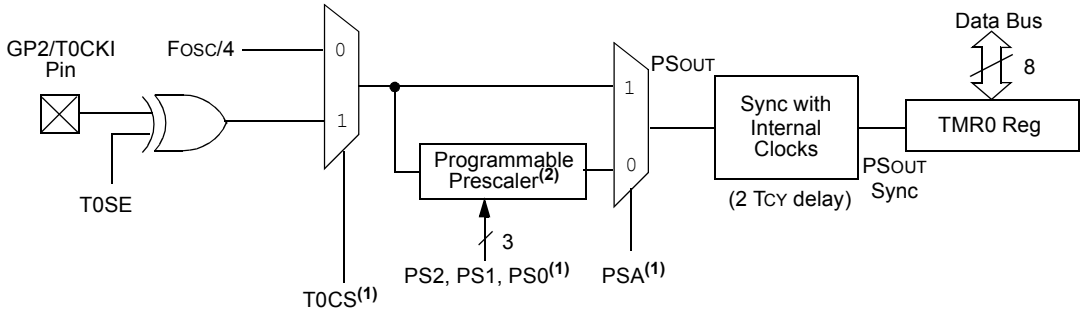
Timer mode is selected by clearing the T0CS bit (OPTION<5>). In Timer mode, the Timer0 module will increment every instruction cycle (without prescaler). If TMR0 register is written, the increment is inhibited for the following two cycles (Figure 6-2 and Figure 6-3). The user can work around this by writing an adjusted value to the TMR0 register.

Counter mode is selected by setting the T0CS bit (OPTION<5>). In this mode, Timer0 will increment either on every rising or falling edge of pin T0CKI. The T0SE bit (OPTION<4>) determines the source edge. Clearing the T0SE bit selects the rising edge. Restrictions on the external clock input are discussed in detail in **Section 6.1 "Using Timer0 With An External Clock"**.

The prescaler may be used by either the Timer0 module or the Watchdog Timer, but not both. The prescaler assignment is controlled in software by the control bit PSA (OPTION<3>). Clearing the PSA bit will assign the prescaler to Timer0. The prescaler is not readable or writable. When the prescaler is assigned to the Timer0 module, prescale values of 1:2, 1:4, 1:256 are selectable. **Section 6.2 "Prescaler"** details the operation of the prescaler.

A summary of registers associated with the Timer0 module is found in Table 6-1.

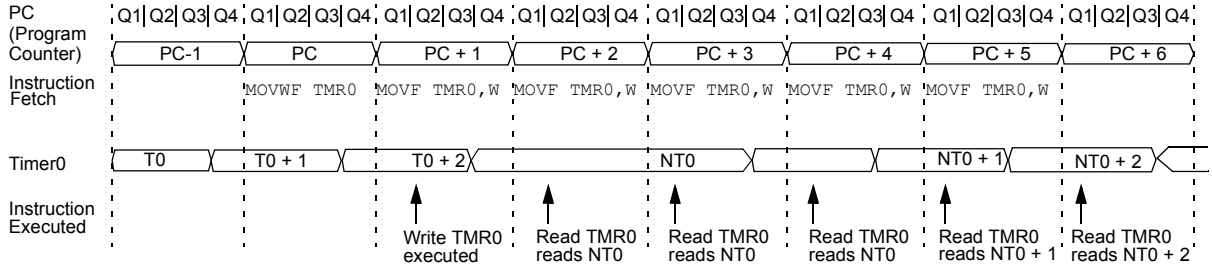
FIGURE 6-1: TIMER0 BLOCK DIAGRAM



Note 1: Bits T0CS, T0SE, PSA, PS2, PS1 and PS0 are located in the OPTION register.

2: The prescaler is shared with the Watchdog Timer (Figure 6-5).

FIGURE 6-2: TIMER0 TIMING: INTERNAL CLOCK/NO PRESCALE



7.9 A/D Acquisition Requirements

For the ADC to meet its specified accuracy, the charge holding capacitor (CHOLD) must be allowed to fully charge to the input channel voltage level. The Analog Input model is shown in Figure 7-1. The source impedance (RS) and the internal sampling switch (RSS) impedance directly affect the time required to charge the capacitor CHOLD. The sampling switch (RSS) impedance varies over the device voltage (VDD), see Figure 7-1. **The maximum recommended impedance for analog sources is 10 kΩ.** As the source impedance is decreased, the acquisition time may be decreased. After the analog input channel is selected (or changed), an A/D acquisition must be done before the conversion can be started. To calculate the minimum acquisition time, Equation 7-1 may be used. This equation assumes that 1/2 LSb error is used (256 steps for the ADC). The 1/2 LSb error is the maximum error allowed for the ADC to meet its specified resolution.

EQUATION 7-1: ACQUISITION TIME EXAMPLE

Assumptions:

Temperature = 50°C and external impedance of 10 kΩ 5.0V VDD

Tacq = Amplifier Settling Time + Hold Capacitor Charging Time + Temperature Coefficient

= TAMP + TC + TCOFF

= 2 μs + TC + [(Temperature - 25°C)(0.05 μs/°C)]

Solving for Tc:

Tc = CHOLD (RIC + RSS + RS) In(1/512)

= -25pF (l kΩ + 7 kΩ + 10 kΩ) In(0.00196)

= 2.81 μs

Therefore:

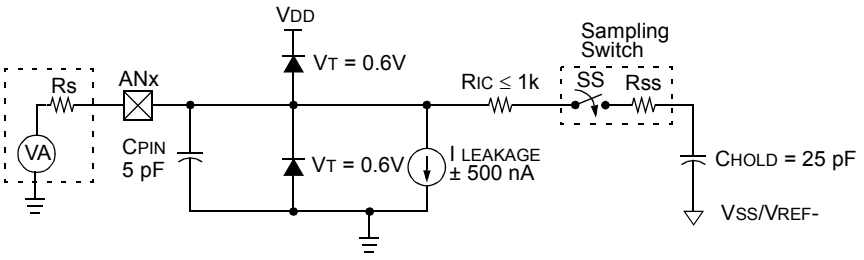
Tacq = 2 μs + 2.81 μs + [(50°C-25°C)(0.0 5μs/°C)]

= 6.06 μs

Note 1: The charge holding capacitor (CHOLD) is not discharged after each conversion.

2: The maximum recommended impedance for analog sources is 10 kΩ. This is required to meet the pin leakage specification.

FIGURE 7-1: ANALOG INPUT MODULE



Legend:

CPIN	=	Input Capacitance
VT	=	Threshold Voltage
ILEAKAGE	=	Leakage current at the pin due to various junctions
RIC	=	Interconnect Resistance
SS	=	Sampling Switch
CHOLD	=	Sample/Hold Capacitance

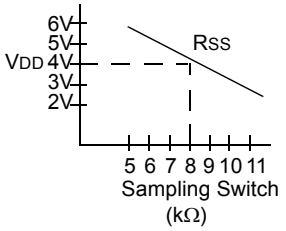


TABLE 9-2: INSTRUCTION SET SUMMARY

Mnemonic, Operands		Description	Cycles	12-Bit Opcode			Status Affected	Notes
				MSb		LSb		
ADDWF	f, d	Add W and f	1	0001	11df	ffff	C,DC,Z	**1,2,4**
ANDWF	f, d	AND W with f	1	0001	01df	ffff	Z	**2,4**
CLRF	f	Clear f	1	0000	011f	ffff	Z	**4**
CLRW	–	Clear W	1	0000	0100	0000	Z	
COMF	f, d	Complement f	1	0010	01df	ffff	Z	
DECF	f, d	Decrement f	1	0000	11df	ffff	Z	**2,4**
DECFSZ	f, d	Decrement f, Skip if 0	1**(2)**	0010	11df	ffff	None	**2,4**
INCF	f, d	Increment f	1	0010	10df	ffff	Z	**2,4**
INCFSZ	f, d	Increment f, Skip if 0	1**(2)**	0011	11df	ffff	None	**2,4**
IORWF	f, d	Inclusive OR W with f	1	0001	00df	ffff	Z	**2,4**
MOVF	f, d	Move f	1	0010	00df	ffff	Z	**2,4**
MOVWF	f	Move W to f	1	0000	001f	ffff	None	**1,4**
NOP	–	No Operation	1	0000	0000	0000	None	
RLF	f, d	Rotate left f through Carry	1	0011	01df	ffff	C	**2,4**
RRF	f, d	Rotate right f through Carry	1	0011	00df	ffff	C	**2,4**
SUBWF	f, d	Subtract W from f	1	0000	10df	ffff	C,DC,Z	**1,2,4**
SWAPF	f, d	Swap f	1	0011	10df	ffff	None	**2,4**
XORWF	f, d	Exclusive OR W with f	1	0001	10df	ffff	Z	**2,4**
BIT-ORIENTED FILE REGISTER OPERATIONS								
BCF	f, b	Bit Clear f	1	0100	bbbf	ffff	None	**2,4**
BSF	f, b	Bit Set f	1	0101	bbbf	ffff	None	**2,4**
BTFSC	f, b	Bit Test f, Skip if Clear	1**(2)**	0110	bbbf	ffff	None	
BTFSS	f, b	Bit Test f, Skip if Set	1**(2)**	0111	bbbf	ffff	None	
LITERAL AND CONTROL OPERATIONS								
ANDLW	k	AND literal with W	1	1110	kkkk	kkkk	Z	
CALL	k	Call subroutine	2	1001	kkkk	kkkk	None	**1**
CLRWDT	k	Clear Watchdog Timer	1	0000	0000	0100	$\overline{TO}$, $\overline{PD}$	
GOTO	k	Unconditional branch	2	101k	kkkk	kkkk	None	
IORLW	k	Inclusive OR Literal with W	1	1101	kkkk	kkkk	Z	
MOVLW	k	Move Literal to W	1	1100	kkkk	kkkk	None	
OPTION	–	Load OPTION register	1	0000	0000	0010	None	
RETLW	k	Return, place Literal in W	2	1000	kkkk	kkkk	None	
SLEEP	–	Go into standby mode	1	0000	0000	0011	$\overline{TO}$, $\overline{PD}$	
TRIS	f	Load TRIS register	1	0000	0000	0fff	None	**3**
XORLW	k	Exclusive OR Literal to W	1	1111	kkkk	kkkk	Z	

Note 1: The 9th bit of the program counter will be forced to a '0' by any instruction that writes to the PC except for GOTO. See **Section 4.7 "Program Counter"**.

2: When an I/O register is modified as a function of itself (e.g., MOVF PORTB, 1), the value used will be that value present on the pins themselves. For example, if the data latch is '1' for a pin configured as input and is driven low by an external device, the data will be written back with a '0'.

3: The instruction TRIS f, where f = 6 causes the contents of the W register to be written to the tri-state latches of PORTB. A '1' forces the pin to a high-impedance state and disables the output buffers.

4: If this instruction is executed on the TMR0 register (and, where applicable, d = 1), the prescaler will be cleared (if assigned to TMR0).

10.0 ELECTRICAL CHARACTERISTICS

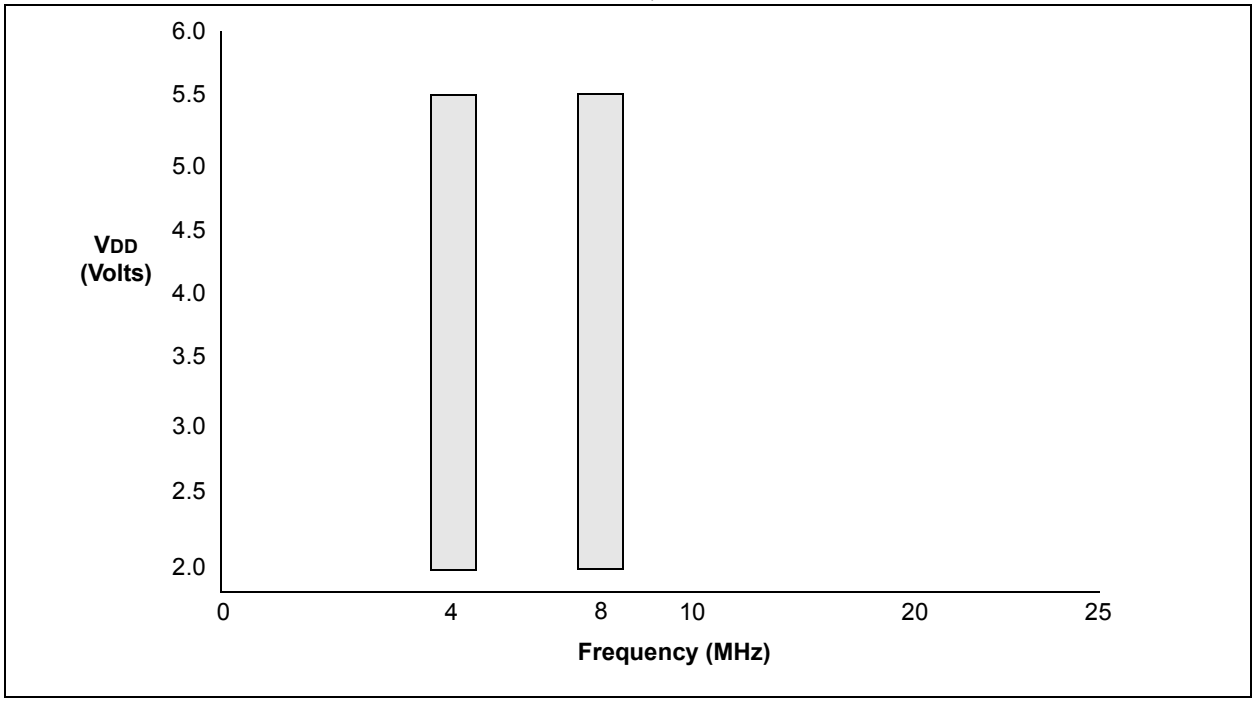
Absolute Maximum Ratings(†)

Ambient temperature under bias ..... -40°C to +125°C
Storage temperature ..... -65°C to +150°C
Voltage on V_{DD} with respect to V_{SS} ..... 0 to +6.5V
Voltage on $\overline{MCLR}$ with respect to V_{SS} ..... 0 to +13.5V
Voltage on all other pins with respect to V_{SS} ..... -0.3V to (V_{DD} + 0.3V)
Total power dissipation(1) ..... 800 mW
Max. current out of V_{SS} pin ..... 80 mA
Max. current into V_{DD} pin ..... 80 mA
Input clamp current, I_{IK} (V_I < 0 or V_I > V_{DD}) ..... ±20 mA
Output clamp current, I_{OK} (V_O < 0 or V_O > V_{DD}) ..... ±20 mA
Max. output current sunk by any I/O pin ..... 25 mA
Max. output current sourced by any I/O pin ..... 25 mA
Max. output current sourced by I/O port ..... 75 mA
Max. output current sunk by I/O port ..... 75 mA

Note 1: Power dissipation is calculated as follows: $P_{DIS} = V_{DD} \times \{I_{DD} - \sum I_{OH}\} + \sum \{(V_{DD} - V_{OH}) \times I_{OH}\} \; .. + \sum(V_{OL} \times I_{OL})$

†NOTICE: Stresses above those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

FIGURE 10-1: VOLTAGE-FREQUENCY GRAPH, -40°C ≤ TA ≤ +125°C



10.1 DC Characteristics: PIC10F220/222 (Industrial)

DC CHARACTERISTICS			Standard Operating Conditions (unless otherwise specified) Operating Temperature -40×C ≤ TA ≤ +85°C (industrial)				
Param No.	**Sym**	**Characteristic**	**Min**	**Typ(1)**	**Max**	**Units**	**Conditions**
D001	VDD	**Supply Voltage**	2.0		5.5	V	See **Figure 10-1**
D002	VDR	**RAM Data Retention Voltage(2)**	1.5*	—	—	V	Device in Sleep mode
D003	VPOR	**VDD Start Voltage** to ensure Power-on Reset	—	Vss	—	V	
D004	SVDD	**VDD Rise Rate** to ensure Power-on Reset	0.05*	—	—	V/ms	
D010	IDD	**Supply Current(3)**					
			— — — —	175 0.625 250 0.800	275 1.1 400 1.5	μA mA μA mA	VDD = 2.0V, Fosc = 4 MHz VDD = 5.0V, Fosc = 4 MHz VDD = 2.0V, Fosc = 8 MHz VDD = 5.0V, Fosc = 8 MHz
D020	IPD	**Power-down Current(4)**					
			— —	0.1 1	1.2 2.4	μA μA	VDD = 2.0V VDD = 5.0V
D022	IWDT	**WDT Current(4)**					
			— —	1.0 7	3 16	μA μA	VDD = 2.0V VDD = 5.0V

* These parameters are characterized but not tested.

Note 1: Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

2: This is the limit to which VDD can be lowered in Sleep mode without losing RAM data.

3: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.

a) The test conditions for all IDD measurements in active operation mode are:
All I/O pins tri-stated, pulled to VSS, T0CKI = VDD, $\overline{MCLR}$ = VDD; WDT enabled/disabled as specified.

b) For standby current measurements, the conditions are the same, except that the device is in Sleep mode.

4: Power-down current is measured with the part in Sleep mode, with all I/O pins in high-impedance state and tied to VDD or VSS. The peripheral current is the sum of the base IPD and the additional current consumed when the peripheral is enabled.

TABLE 10-1: PULL-UP RESISTOR RANGES

VDD (Volts)	Temperature (°C)	Min	Typ	Max	Units
GP0/GP1					
2.0	-40	73K	105K	186K	Ω
	25	73K	113K	187K	Ω
	85	82K	123K	190K	Ω
	125	86K	132k	190K	Ω
5.5	-40	15K	21K	33K	Ω
	25	15K	22K	34K	Ω
	85	19K	26k	35K	Ω
	125	23K	29K	35K	Ω
GP3					
2.0	-40	63K	81K	96K	Ω
	25	77K	93K	116K	Ω
	85	82K	96k	116K	Ω
	125	86K	100K	119K	Ω
5.5	-40	16K	20k	22K	Ω
	25	16K	21K	23K	Ω
	85	24K	25k	28K	Ω
	125	26K	27K	29K	Ω

10.4 Timing Parameter Symbology and Load Conditions

The timing parameter symbols have been created following one of the following formats:

1. TppS2ppS
2. TppS

T			
F	Frequency	T	Time

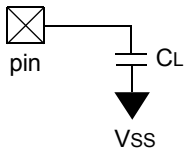
Lowercase subscripts (pp) and their meanings:

pp			
2	to	mc	$\overline{MCLR}$
ck	CLKOUT	osc	Oscillator
cy	Cycle time	os	OSC1
drt	Device Reset Timer	t0	T0CKI
io	I/O port	wdt	Watchdog Timer

Uppercase letters and their meanings:

S			
F	Fall	P	Period
H	High	R	Rise
I	Invalid (high-impedance)	V	Valid
L	Low	Z	High-impedance

FIGURE 10-2: LOAD CONDITIONS



Legend:
C_L = 50 pF for all pins

TABLE 10-2: CALIBRATED INTERNAL RC FREQUENCIES – PIC10F220/222

AC CHARACTERISTICS			Standard Operating Conditions (unless otherwise specified) Operating Temperature -40°C ≤ TA ≤ +85°C (industrial), -40°C ≤ TA ≤ +125°C (extended) Operating Voltage VDD range is described in **Section 10.1 "DC Characteristics: PIC10F220/222 (Industrial)"**.					
Param No.	**Sym**	**Characteristic**	**Freq. Tolerance**	**Min**	**Typ†**	**Max**	**Units**	**Conditions**
F10	FOSC	Internal Calibrated INTOSC Frequency(1, 2, 3)	± 1%	3.96	4.00	4.04	MHz	VDD=3.5V @ 25°C
			± 2%	3.92	4.00	4.08	MHz	2.5V ≤ VDD ≤ 5.5V 0°C ≤ TA ≤ +85°C (industrial)
			± 5%	3.80	4.00	4.20	MHz	2.0V ≤ VDD ≤ 5.5V -40°C ≤ TA ≤ +85°C (industrial) -40°C ≤ TA ≤ +125°C (extended)

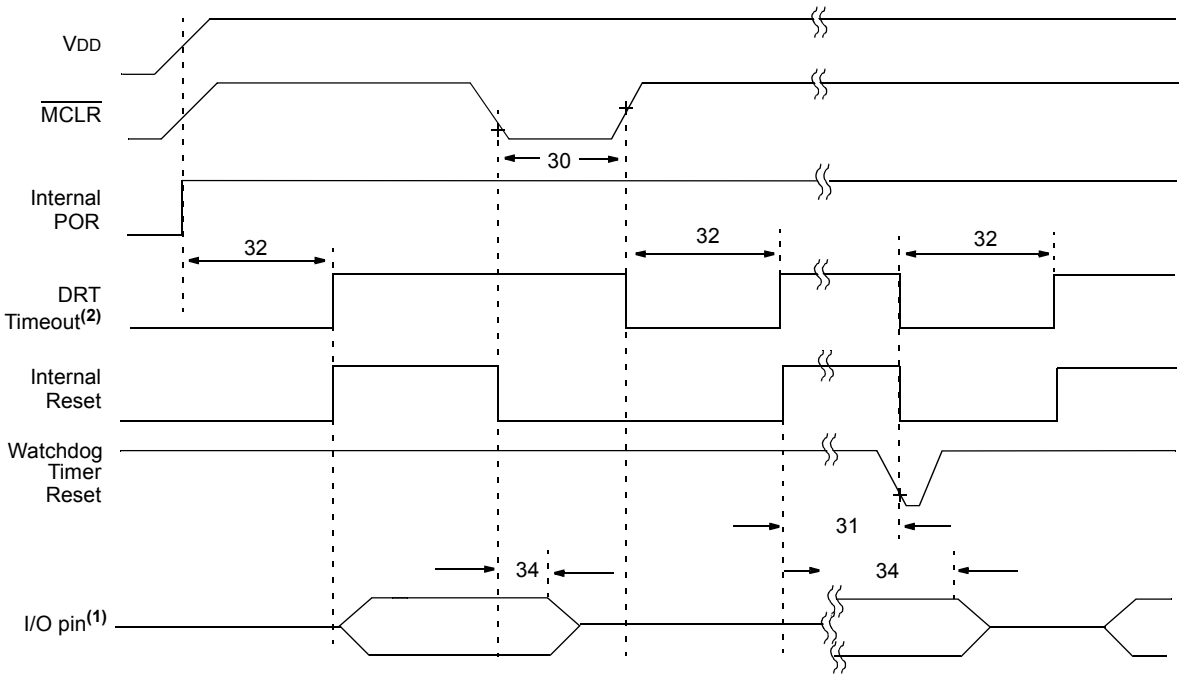
† Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: To ensure these oscillator frequency tolerances, VDD and VSS must be capacitively decoupled as close to the device as possible. 0.1 μF and 0.01 μF values in parallel are recommended.

2: Under stable VDD conditions.

3: Frequency values in this table are doubled when the 8 MHz INTOSC option is selected.

FIGURE 10-3: RESET, WATCHDOG TIMER AND DEVICE RESET TIMER TIMING



Note 1: I/O pins must be taken out of High-impedance mode by enabling the output drivers in software.
2: Runs on POR Reset only.

TABLE 10-3: RESET, WATCHDOG TIMER AND DEVICE RESET TIMER – PIC10F220/222

AC CHARACTERISTICS			Standard Operating Conditions (unless otherwise specified) Operating Temperature -40°C ≤ TA ≤ +85°C (industrial) -40°C ≤ TA ≤ +125°C (extended) Operating Voltage VDD range is described in **Section 10.1 "DC Characteristics: PIC10F220/222 (Industrial)"**				
Param No.	**Sym**	**Characteristic**	**Min**	**Typ(1)**	**Max**	**Units**	**Conditions**
30	T_{MCL}	$\overline{MCLR}$ Pulse Width (low)	2* 5*	— —	— —	µs µs	VDD = 5V, -40°C to +85°C VDD = 5.0V
31	TWDT	Watchdog Timer Time-out Period (no prescaler)	10 10	18 18	29 31	ms ms	VDD = 5.0V (Industrial) VDD = 5.0V (Extended)
32	TDRT*	Device Reset Timer Period (standard)	0.600 0.600	1.125 1.125	1.85 1.95	ms ms	VDD = 5.0V (Industrial) VDD = 5.0V (Extended)
34	TIOZ	I/O High-impedance from $\overline{MCLR}$ low	—	—	2*	µs	

* These parameters are characterized but not tested.

Note 1: Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

11.0 DC AND AC CHARACTERISTICS GRAPHS AND TABLES.

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore, outside the warranted range.

"Typical" represents the mean of the distribution at 25°C. "Maximum" or "minimum" represents (mean + 3σ) or (mean - 3σ) respectively, where s is a standard deviation, over each temperature range.

FIGURE 11-1: IDD vs. VDD OVER FOSC (4 MHz)

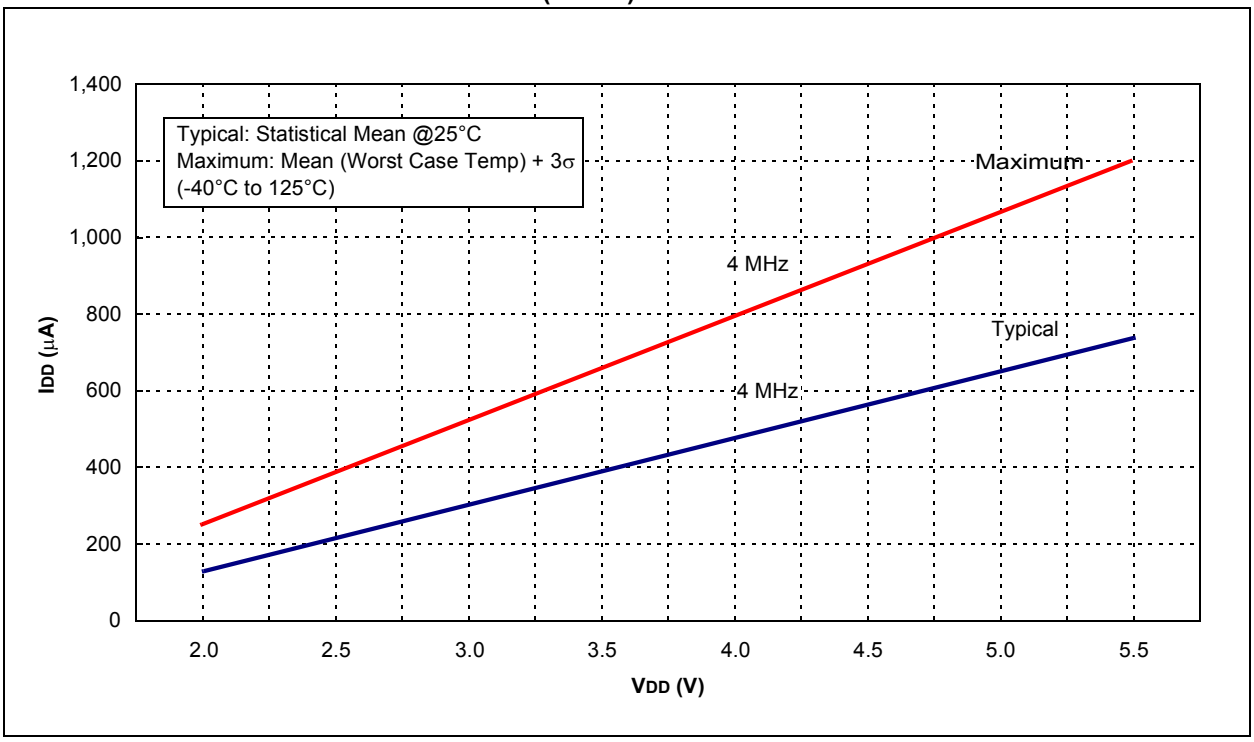


FIGURE 11-2: IDD vs. VDD OVER FOSC (8 MHz)

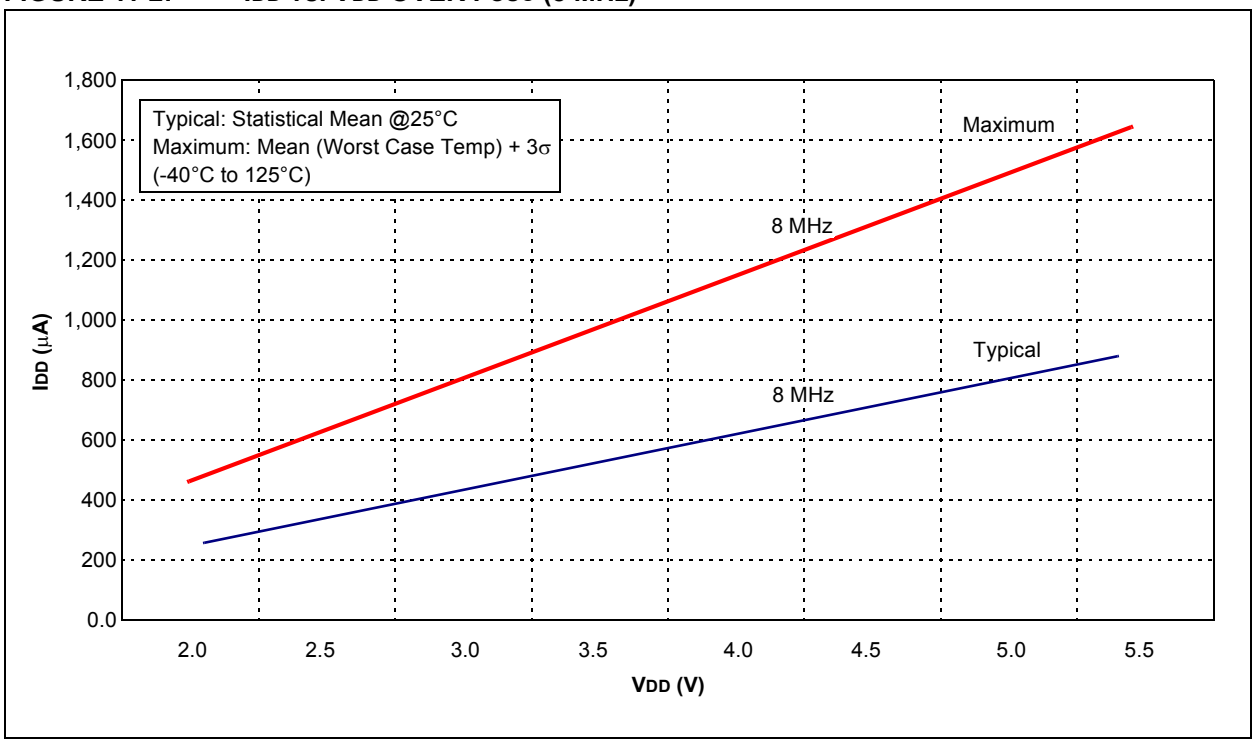


FIGURE 11-3: TYPICAL IPD vs. VDD (SLEEP MODE, ALL PERIPHERALS DISABLED)

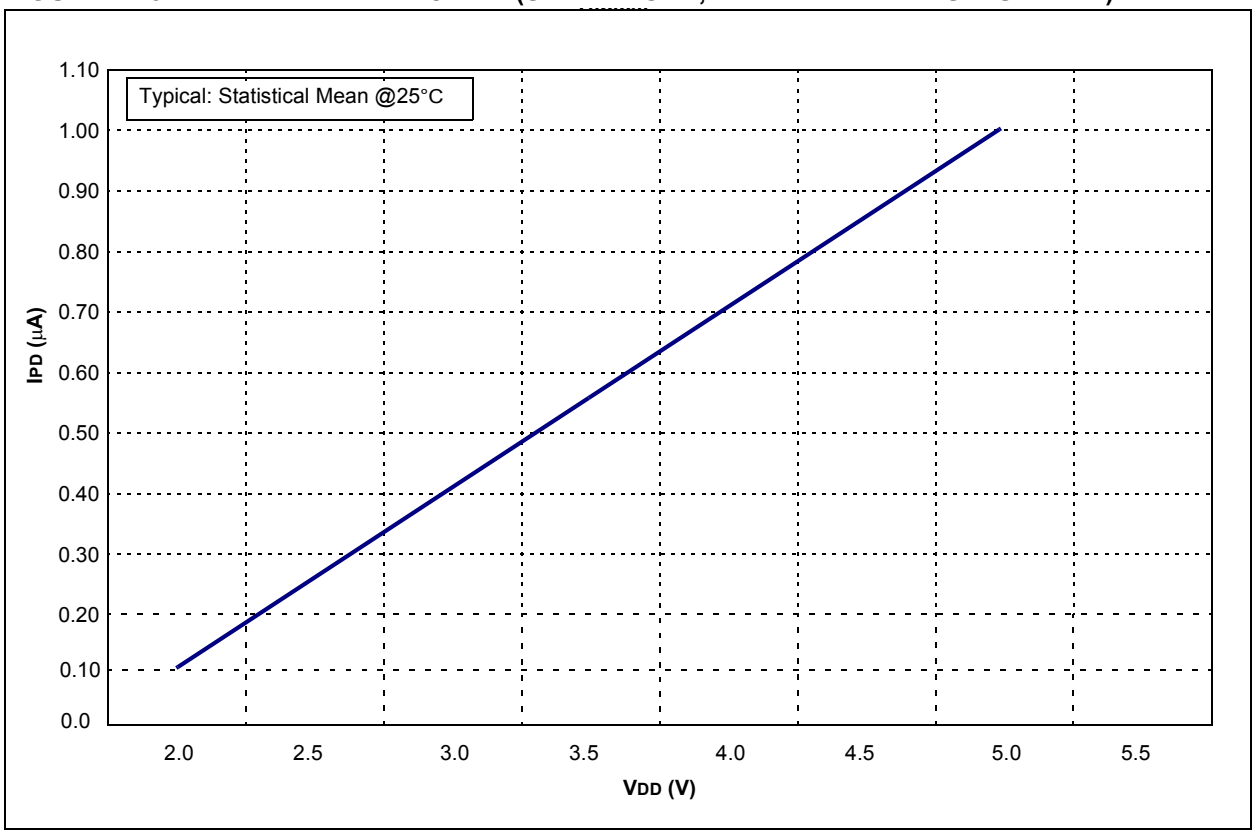


FIGURE 11-6: MAXIMUM WDT IPD vs. VDD OVER TEMPERATURE

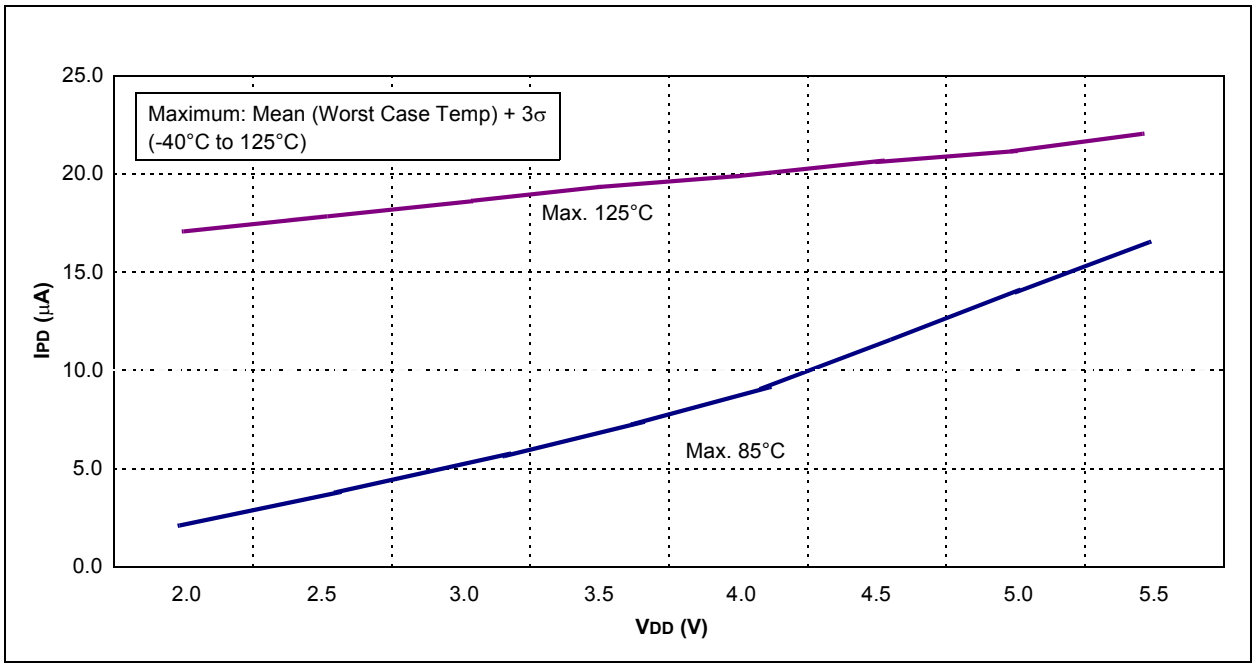


FIGURE 11-7: WDT TIME-OUT vs. VDD OVER TEMPERATURE (NO PRESCALER)

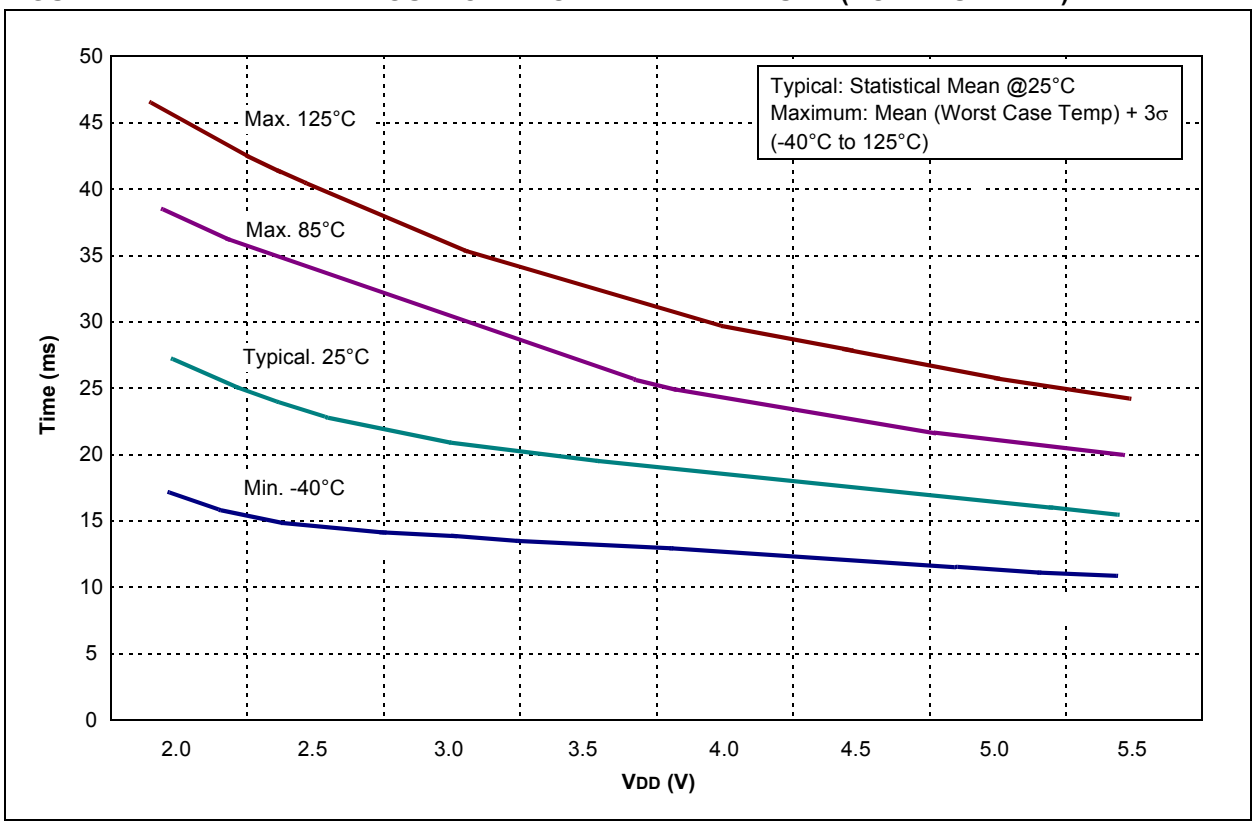


FIGURE 11-8: VOL vs. IOL OVER TEMPERATURE (VDD = 3.0V)

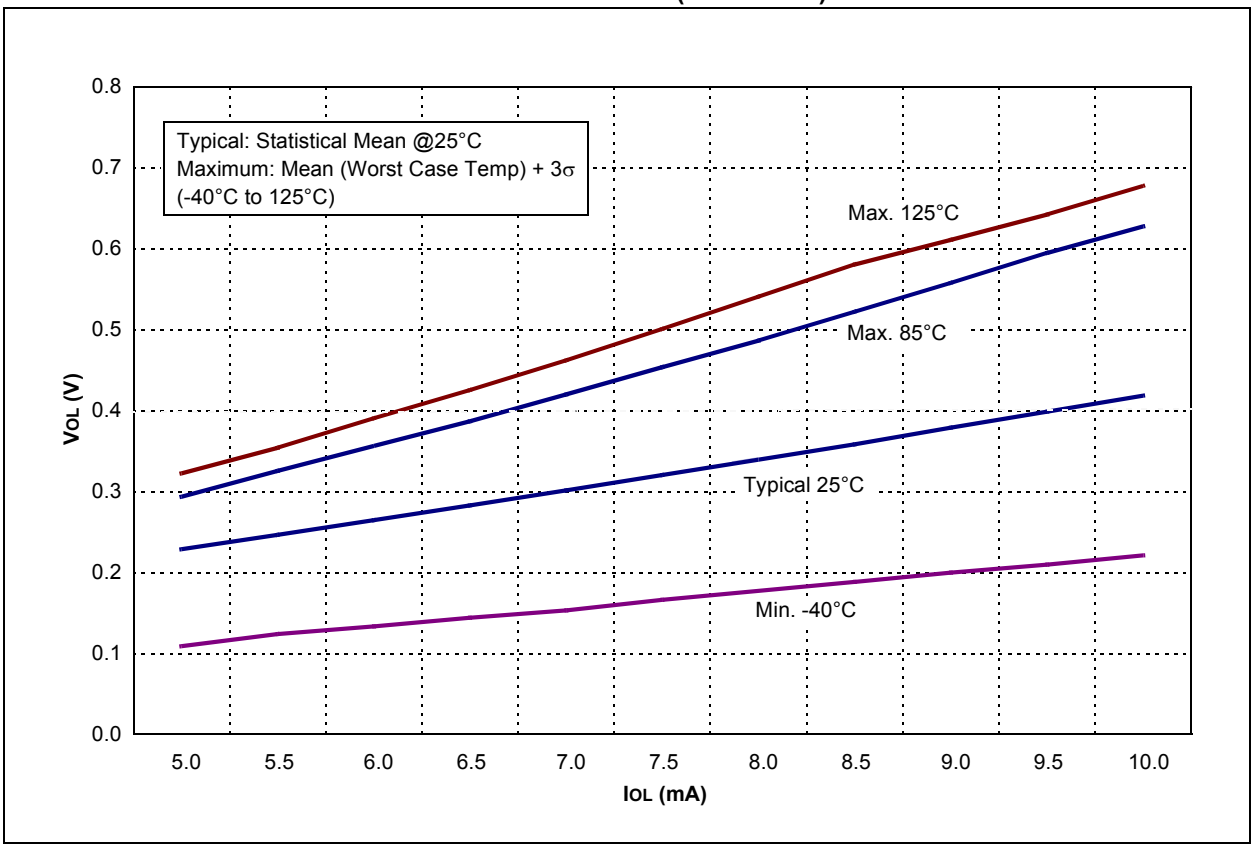
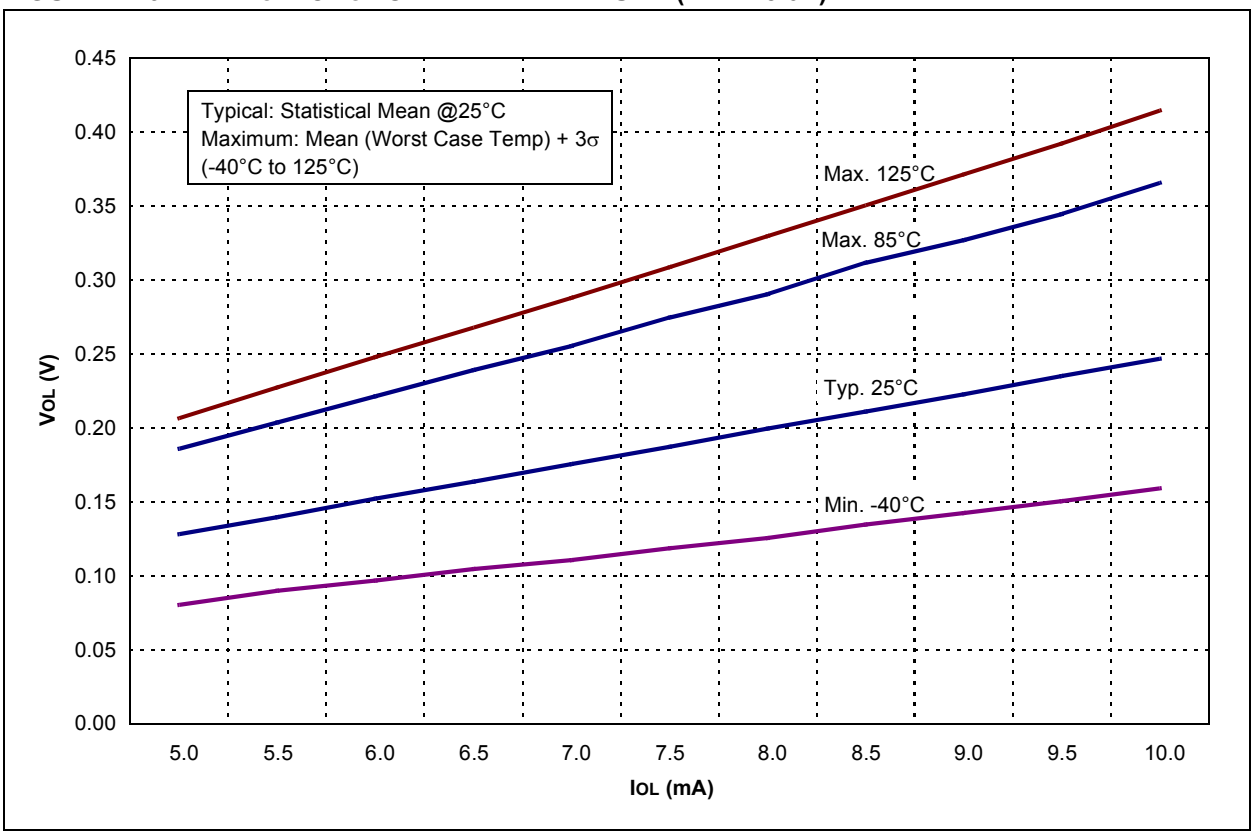


FIGURE 11-9: VOL vs. IOL OVER TEMPERATURE (VDD = 5.0V)



12.0 DEVELOPMENT SUPPORT

The PIC® microcontrollers (MCU) and dsPIC® digital signal controllers (DSC) are supported with a full range of software and hardware development tools:

- Integrated Development Environment
  - MPLAB® X IDE Software
- Compilers/Assemblers/Linkers
  - MPLAB XC Compiler
  - MPASM™ Assembler
  - MPLINK™ Object Linker/ MPLIB™ Object Librarian
  - MPLAB Assembler/Linker/Librarian for Various Device Families
- Simulators
  - MPLAB X SIM Software Simulator
- Emulators
  - MPLAB REAL ICE™ In-Circuit Emulator
- In-Circuit Debuggers/Programmers
  - MPLAB ICD 3
  - PICkit™ 3
- Device Programmers
  - MPLAB PM3 Device Programmer
- Low-Cost Demonstration/Development Boards, Evaluation Kits and Starter Kits
- Third-party development tools

12.1 MPLAB X Integrated Development Environment Software

The MPLAB X IDE is a single, unified graphical user interface for Microchip and third-party software, and hardware development tool that runs on Windows®, Linux and Mac OS® X. Based on the NetBeans IDE, MPLAB X IDE is an entirely new IDE with a host of free software components and plug-ins for high-performance application development and debugging. Moving between tools and upgrading from software simulators to hardware debugging and programming tools is simple with the seamless user interface.

With complete project management, visual call graphs, a configurable watch window and a feature-rich editor that includes code completion and context menus, MPLAB X IDE is flexible and friendly enough for new users. With the ability to support multiple tools on multiple projects with simultaneous debugging, MPLAB X IDE is also suitable for the needs of experienced users.

Feature-Rich Editor:

- Color syntax highlighting
- Smart code completion makes suggestions and provides hints as you type
- Automatic code formatting based on user-defined rules
- Live parsing

User-Friendly, Customizable Interface:

- Fully customizable interface: toolbars, toolbar buttons, windows, window placement, etc.
- Call graph window

Project-Based Workspaces:

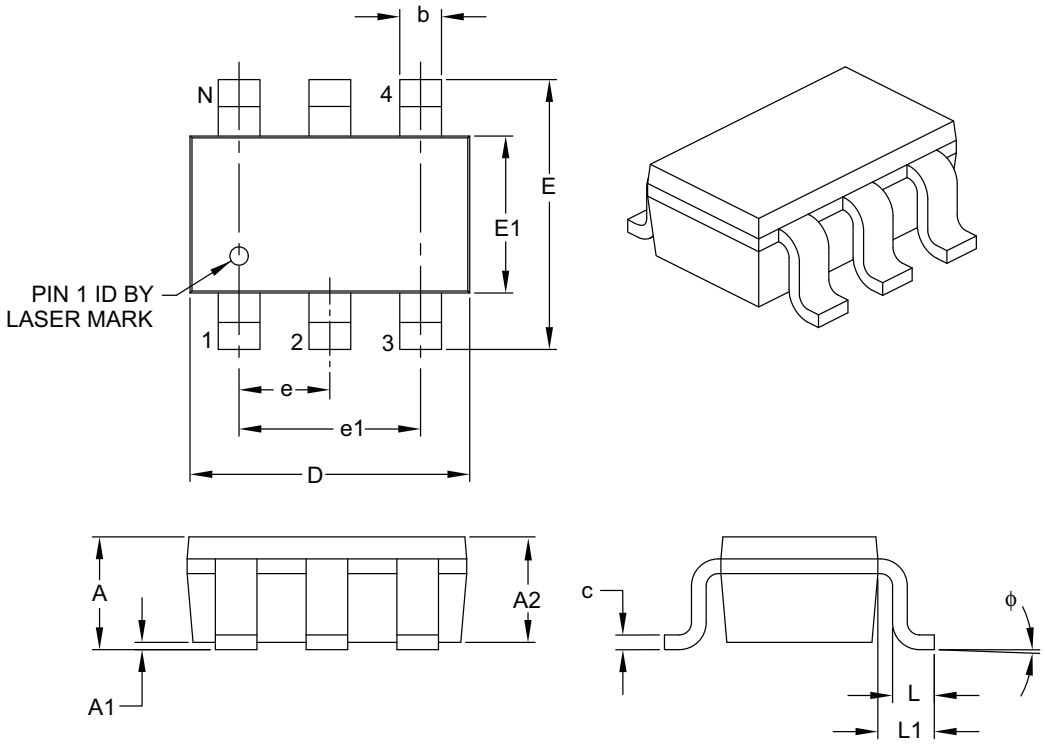
- Multiple projects
- Multiple tools
- Multiple configurations
- Simultaneous debugging sessions

File History and Bug Tracking:

- Local file history feature
- Built-in support for Bugzilla issue tracker

6-Lead Plastic Small Outline Transistor (OT) [SOT-23]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		6	
Pitch	e		0.95 BSC	
Outside Lead Pitch	e1		1.90 BSC	
Overall Height	A	0.90	–	1.45
Molded Package Thickness	A2	0.89	–	1.30
Standoff	A1	0.00	–	0.15
Overall Width	E	2.20	–	3.20
Molded Package Width	E1	1.30	–	1.80
Overall Length	D	2.70	–	3.10
Foot Length	L	0.10	–	0.60
Footprint	L1	0.35	–	0.80
Foot Angle	ϕ	0°	–	30°
Lead Thickness	c	0.08	–	0.26
Lead Width	b	0.20	–	0.51

Notes:

1. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.127 mm per side.
2. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-028B

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